

Form PTO-1449

# INFORMATION DISCLOSURE CITATION IN AN APPLICATION

(Use several sheets if necessary)

ATTY DOCKET NO.  
3672-0144P

APPLICATION NO.  
10/088,913

APPLICANT  
THOMPSON, et al.

FILING DATE  
March 25, 2002

GROUP

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
JMA	4,982,368	1991-01-01	ARIMOTO	365	206	
JMA	4,599,709	1986-07-08	CLEMONS	365	200	

## FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION	
						YES	NO
JMA	0486901A2	1992-05-27	EUROPE			X	

**OTHER DOCUMENTS** (Include Name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.

JMA	HIRANO, et al., "2V/100ns 1T/1C Nonvolatile Ferroelectric Memory Architecture with Bitline-Driven Read Scheme & non-Relaxation Reference Cell", 1996 Symposium on VLSI Circuits Digest of Technical Papers, 1996 IEEE, pages 48-49.

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.